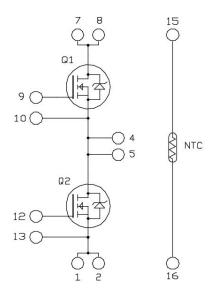
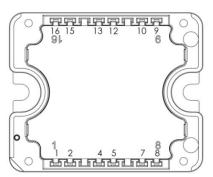
MSCSM70AM19T1AG

Phase Leg SiC MOSFET Power Module

Product Overview

The MSCSM70AM19T1AG device is a full bridge 700V, 124A silicon carbide (SiC) power module.





Notes:

- Pins 1/2; 4/5; 7/8 must be shorted together.
- All ratings at T_J = 25 °C, unless otherwise specified.

⚠ CAUTION

These devices are sensitive to electrostatic discharge. Proper handling procedures must be followed.

Features

The following are key features of the MSCSM70AM19T1AG device:

- SiC Power MOSFET
 - High speed switching
 - Low R_{DS(on)}
 - Ultra low loss
- · Kelvin source for easy drive
- Very low stray inductance
- Internal thermistor for temperature monitoring
- Aluminum Nitride (AIN) substrate for improved thermal performance

Benefits

The following are the benefits of MSCSM70AM19T1AG device:

- High efficiency converter
- Outstanding performance at high frequency operation
- Solderable terminals both for power and signal for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction-to-case thermal resistance
- Low profile
- RoHS compliant

Application

The MSCSM70AM19T1AG device is designed for the following applications:

- · Welding converters
- Switched mode power supplies
- Uninterruptible power supplies
- EV motor and traction drive

DS00004605A-page 2 **Data Sheet**

1. Electrical Specifications

This section provides the electrical specifications of the MSCSM70AM19T1AG device.

1.1 SiC MOSFET Characteristics (Per SiC MOSFET)

The following table lists the absolute maximum ratings per SiC MOSFET of the MSCSM70AM19T1AG device.

Table 1-1. Absolute Maximum Ratings

Symbol	Parameter		Maximum Ratings	Unit	
V _{DSS}	Drain-Source voltage	rain-Source voltage		V	
I _D	0 1 1		124 ¹	Α	
			981		
I _{DM}	Pulsed drain current	Pulsed drain current			
V _{GS}	Gate-Source voltage	Gate-Source voltage		V	
R _{DS(on)}	Drain-Source ON resistance		19	mΩ	
P _D	Power dissipation	T _C = 25 °C	365	W	

Note:

The following table lists the electrical characteristics per SiC MOSFET of the MSCSM70AM19T1AG device.

Table 1-2. Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min.	Тур.	Max.	Unit
I _{DSS}	Zero gate voltage drain current	V _{GS} = 0V V _{DS} = 700V		_	_	100	μΑ
R _{DS(on)}	Drain-Source on	V _{GS} = 20V	T _J = 25 °C	_	15	19	mΩ
	resistance	I _D = 40A	T _J = 175 °C	_	18.8	_	
V _{GS(th)}	Gate threshold voltage	$V_{GS} = V_{DS}$ $I_D = 4 \text{ mA}$		1.9	2.4	_	V
I _{GSS}	Gate–Source leakage current	$V_{GS} = 20V; V_{DS} = 0$	V	_	_	150	nA

^{1.} Specification of SiC MOSFET device but output current must be limited due to size of power connectors.

The following table lists the dynamic characteristics per SiC MOSFET of the MSCSM70AM19T1AG device.

Table 1-3. Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min.	Тур.	Max.	Unit
C _{iss}	Input capacitance	V _{GS} = 0V		_	4500	_	pF
C _{oss}	Output capacitance	V _{DS} = 700V		_	510	_	
C _{rss}	Reverse transfer capacitance	f = 1 MHz		_	29	_	
Qg	Total gate charge	V _{GS} = -5V/20V		_	215	_	nC
Q _{gs}	Gate-Source charge	V _{Bus} = 470V		_	58	_	
Q_{gd}	Gate-Drain charge	I _D = 40A		_	35	_	
T _{d(on)}	Turn-on delay time	V _{GS} = -5V/20V	T _J = 150°C	_	40	_	ns
T _r	Rise time	$V_{\text{Bus}} = 400V$ $I_{\text{D}} = 80A$		_	40	_	
T _{d(off)}	Turn-off delay time		_	50	_		
T _f	Fall time	$R_{G(on)} = 68\Omega$ $R_{G(off)} = 4.7\Omega$			20	_	
Eon	Turn-on energy	V _{GS} = -5V/20V	T _J = 150 °C	_	893	_	μJ
E _{off}	Turn-off energy	$V_{Bus} = 400V$ $I_{D} = 80A$ $R_{G(on)} = 68\Omega$ $R_{G(off)} = 4.7\Omega$	T _J = 150 °C	_	194	_	
R _{Gint}	Internal gate resistance			_	0.69	_	Ω
R _{thJC}	Junction-to-case thermal res	sistance		_	_	0.41	°C/W

The following table lists the body diode ratings and characteristics per SiC MOSFET of the MSCSM70AM19T1AG device.

Table 1-4. Body Diode Ratings and Characteristics

Symbol	Characteristic	Test Conditions	Min.	Тур.	Max.	Unit
V _{SD}	Diode forward voltage	$V_{GS} = 0V; I_{SD} = 40A$	_	3.4	_	V
		$V_{GS} = -5V$; $I_{SD} = 40A$	_	3.8	_	
t _{rr}	Reverse recovery time	$I_{SD} = 40A; V_{GS} = -5V$	_	38	_	ns
Q _{rr}	Reverse recovery charge	$V_R = 400V$; $di_F/dt = 1000 A/\mu s$	_	318	_	nC
I _{rr}	Reverse recovery current		_	14.8	_	Α

1.2 Thermal and Package Characteristics

The following table lists the thermal and package characteristics of the MSCSM70AM19T1AG device.

Table 1-5. Thermal and Package Characteristics

Symbol	Characteristics	Characteristics				Unit
V _{ISOL}	RMS isolation voltage, any termi	RMS isolation voltage, any terminal to case t =1 min, 50 Hz/60 Hz			_	V
T _J	Operating junction temperature	Operating junction temperature range			175	°C
T _{JOP}	Recommended junction tempera	Recommended junction temperature under switching conditions			T _{Jmax} –25	
T _{STG}	Storage temperature range	Storage temperature range				
T _C	Operating case temperature	Operating case temperature			125	
Torque	Mounting torque	To heatsink	M4	2	3	N.m
Wt	Package weight			_	80	g

The following table lists the temperature sensor NTC of the MSCSM70AM19T1AG device.

Table 1-6. Temperature Sensor NTC

Symbol	Characteristic		Min	Тур	Max	Unit
R ₂₅	Resistance at 25°C		_	50	_	kΩ
$\Delta R_{25}/R_{25}$	_	_	_	5	_	%
B _{25/85}	T ₂₅ = 298.15 K	_	_	3952	_	K
ΔΒ/Β	_	T _C = 100 °C	_	4	_	%

$$R_{T} = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$
 T: Thermistor temperature R_T: Thermistor value at T

Note: See APT0406—Using NTC Temperature Sensor Integrated into Power Module for more information.

1.3 Typical SiC MOSFET Performance Curve

This section shows the typical SiC MOSFET performance curves of the MSCSM70AM19T1AG device.

Figure 1-1. Maximum Thermal Impedance

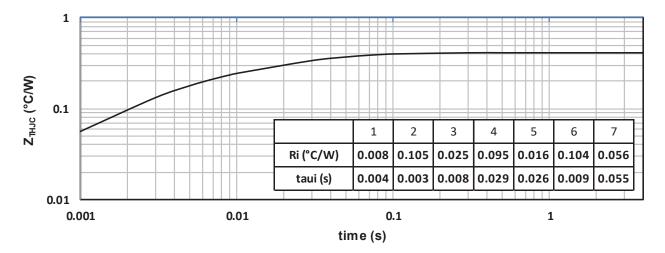


Figure 1-2. Output Characteristics, $T_J = 25$ °C

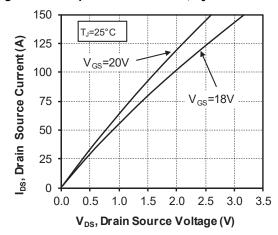


Figure 1-4. Normalized R_{DS(on)} vs. Temperature

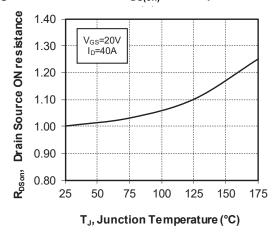


Figure 1-3. Output Characteristics, T_J = 175 °C

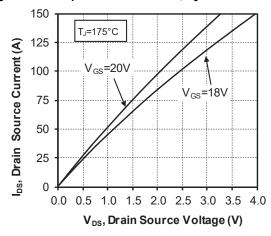


Figure 1-5. Transfer Characteristics

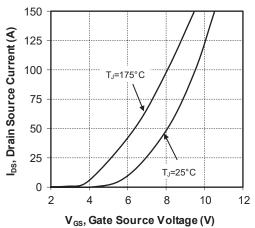


Figure 1-6. Switching Energy vs. Current

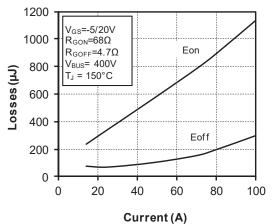


Figure 1-7. Turn On Energy vs. Rg

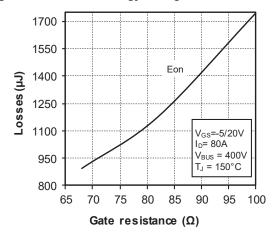


Figure 1-8. Capacitance vs. Drain Source Voltage

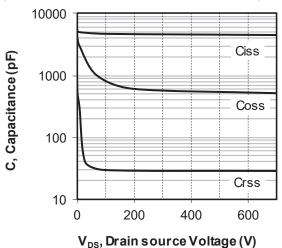


Figure 1-9. Gate Charge vs. Gate Source Voltage

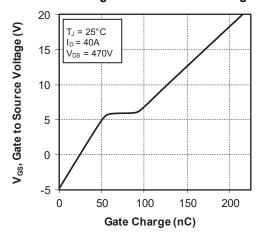


Figure 1-10. Body Diode Characteristics, T_J = 25 °C

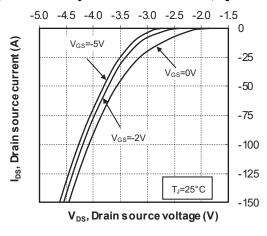


Figure 1-11. 3rd Quadrant Characteristics, T_J = 25 °C

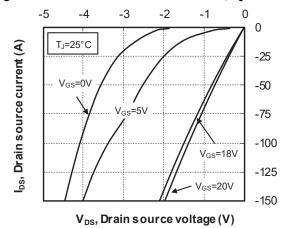
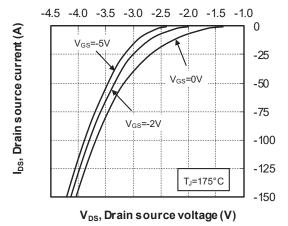


Figure 1-12. Body Diode Characteristics, T_J = 175 °C Figure 1-13. 3rd Quadrant Characteristics, T_J = 175 °C



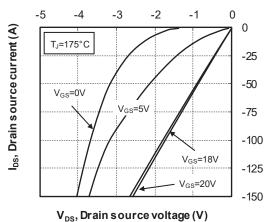


Figure 1-14. Operating Frequency vs Drain Current

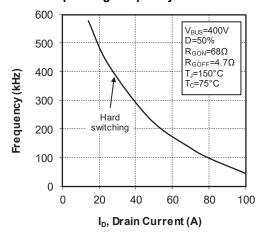
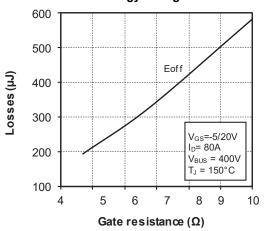


Figure 1-15. Turn Off Energy vs. Rg



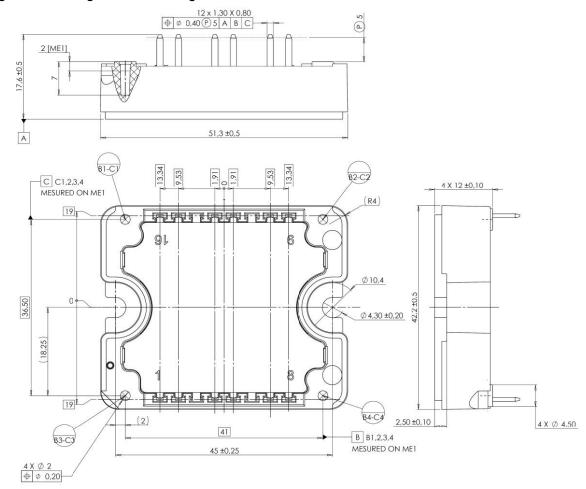
2. Package Specifications

The following section shows the package specification of the MSCSM70AM19T1AG device.

2.1 Package Outline

The following figure shows the package outline drawing of the MSCSM70AM19T1AG device. The dimensions in the following figure are in millimeters.

Figure 2-1. Package Outline Drawing



Note: See AN3500A—Mounting Instructions for SP1F and SP3F Power Modules for more information.

MSCSM70AM19T1AG

Revision History

3. Revision History

Revision	Date	Description
Α	06/2022	Initial Revision

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